Enhanced flux pinning in $YBa_2Cu_3O_{7-\delta}$ films by nanoscaled substrate surface roughness

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Nanoscaled substrate surface roughness is shown to strongly influence the critical current density (J_c) in YBa₂Cu₃O_{7- δ} (YBCO) films made by pulsed-laser deposition on the crystalline LaAlO₃ substrates consisting of two separate twin-free and twin-rich regions. The nanoscaled corrugated substrate surface was created in the twin-rich region during the deposition process. Using magneto-optical imaging techniques coupled with optical and atomic force microscopy, we observed an enhanced flux pinning in the YBCO films in the twin-rich region, resulting in a ~30% increase in J_c , which was unambiguously confirmed by the direct transport measurement. © 2005 American Institute of Physics. [DOI: 10.1063/1.2051794]

In large-scale applications of high T_c superconductors (HTS), the key candidates are the so-called second generation coated conductors, where YBa₂Cu₃O_{7-δ} (YBCO) films are deposited on buffered metal substrates biaxially aligned.¹ Two of the leading factors for limiting J_c in YBCO-coated conductors are the degree of texture and surface roughness of the buffered metal substrate. The former stems from the grain boundary problem; that is, boundaries between misaligned YBCO grains carry significantly lower J_c than the grains. This has been thoroughly studied using YBCO films grown on SrTiO₃ (STO) bicrystal substrate.² Recently, Foltyn and co-workers achieved very high J_c in YBCO-coated conductors on electropolished Hastelloy® C276 substrate.³ However, it was not clear whether the enhancement was due to the smoother substrate surface or to the improved in-plane texture of the buffer layer.

The goal of this work is to perform a study where the influence of substrate surface roughness on the J_c in YBCO films can be isolated. We took advantage of the surface reconstruction of twined LaAlO₃ (LAO) single-crystal substrates to produce a surface roughness of 2–6 nm typically found on the surface of metal substrates used for YBCO-coated conductors. Unlike STO or MgO substrates, LAO crystals are usually heavily twinned due to its orthorhombicity. Among commercially available large LAO crystal wafers (\sim 5 cm diameter), it is sometimes possible to find small twin-free regions. Hence, a substrate can be selected which consists of two regions, one twinned and one twin-free.

The equilibrium high-temperature cubic (HTC) perovskite to low-temperature orthorhombic (LTO) transition temperature of LAO is ~544 °C. However, there is significant hysteresis. In fact, even when orthorhombic substrates are heated to a typical deposition temperature of 800 °C, the orthorhombic structure is retained for a while. At the deposition temperature, the orthorhombic surface reconstructs, which results in a corrugated surface with a relief depth of

^{~4.5} nm.^{4,5} In Fig. 1, we illustrated the process we utilized in a schematic drawing of *LTO twinned area* of a selected LAO single-crystal substrate having both twinned and twinfree regions. Figure 1(a) illustrates the first step, where the LAO (100) surface is polished to subnanometer smoothness. In the next step the substrate is brought to pulsed-laser deposition (PLD) temperature (790 °C). The LAO does not transform to HTC during the deposition time, but the heating does allow surface reconstruction of the (100) LTO surface prior to deposition, to provide the desired surface roughness of

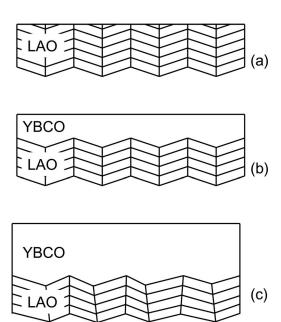


FIG. 1. Schematic drawing illustrating the formation of a nanoscaled corrugated interface between YBCO and twinned LAO substrate. (a) (100) cut and polished LAO at room temperature with natural twin domains. (b) Initial deposition of YBCO films on LAO at ~790 °C, where (100) surface reconstruction at high temperature leads to a corrugation on LAO surface prior to the deposition. (c) The corrugated interface between YBCO and LAO when sample is cooled to room temperature, where possible twin domain motion in LAO is also shown.

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FIG. 2. The corresponding MOI, optical microscopy, and AFM taken on the same 0.2 μ m thick YBCO film strip (0.8 mm wide). (a) MOI was taken at 30 K and external field B_a =50 mT applied to the ZFC sample. (b) and (c) Optical images, taken at left and right ends of the film strip, respectively, show the twin-free region (b) at the far left end of the strip, while the twin-rich region occupied the rest of the substrate, which included the right end of the strip (c). In the dotted areas, microbridges (shown in enlarged view at bottom) were patterned for direct transport J_c measurement, after MOI and AFM analysis. (d) and (e) AFM images of the film in the twin-free and the twin-rich regions, respectively.

~4.5 nm. Deposition of YBCO takes place onto the corrugated LAO [Fig. 1(b)]. Note that at the same time, on another portion of the substrate, deposition takes place on the flat twin-free region. This allows a direct comparison of YBCO films deposited under identical conditions onto the corrugated twinned and smooth twin-free LAO substrate. Figure 1(c) shows the corrugated interface between YBCO and twinned LAO substrate when sample is cooled to room temperature, where possible twin motion is also illustrated. Specifically, in this study the c-axis oriented 0.2 μ m thick YBCO films were grown using a KrF excimer laser on such selected (100) LAO substrates polished to subnanometer smoothness. The substrates were heated to 790 °C, and the 5 min deposition took place in an oxygen environment of 100 mTorr. Subsequently, samples were brought to room temperature at ~ 60 °C/min. The films were of good quality, with superconducting transition temperature T_c =89.2 K and $\Delta T_c \sim 1.5$ K. Transport $J_c (\sim 6 \times 10^6 \text{ A/cm}^2)$ at 77 K is comparable to that of the best YBCO films deposited on STO.⁶

Magneto-optical imaging (MOI) studies were performed using a low-temperature MOI station described previously. A high-resolution garnet MOI indicator film was placed directly onto the sample surface, with magnetic field B_a always applied perpendicular to the film surface, and polarizer and analyzer crossed at 90°. Brightness intensity in a MOI image is proportional to the local magnetic field normal to the surface of the film. To coordinate the MOI studies, both optical and atomic force microscopy (AFM) were used to examine the surface of the YBCO films, as well as the underlying substrate surface after removal of the YBCO films. Transmission electron microscopy (TEM) was used to evaluate the microstructures at YBCO-LAO interface.

Figure 2 shows the corresponding images of one $0.2~\mu m$ trogen temperature using 0.5~ms (settle time) pulse current to Downloaded 06 Jan 2006 to 130.199.3.16. Redistribution subject to AIP license or copyright, see http://apl.aip.org/apl/copyright.jsp

thick YBCO film patterned into an 0.8 mm wide strip, (a) MOI, (b) (c) optical microscopy, and (d) (e) AFM. MOI shown in Figure 2(a) was taken at 30 K and B_a =50 mT applied to the zero-field-cooled (ZFC) sample. Small notches at the edge of the films indicated by the arrows were due to fabrication/handling of the films.^{7,8} In general, a uniform flux penetration was observed and consistent with the prediction of the critical state model for a type II superconducting film.^{7,8}

Figures 2(b) and 2(c) are the optical images of the film taken at left and right ends, respectively. The twin-free region was at the far left end of the YBCO strip, while the twin-rich region occupied the rest of the substrate which included the right end of the film as shown in Fig. 2(c). Magnetic flux clearly penetrated deeper into the sample at the left twin-free region than that at the right twin-rich region, suggesting a different flux pinning strength. The LAO substrate twin domains with a width of $30-100 \mu m$ can be seen through the 0.2 μ m thick YBCO film, as well as on the area where the YBCO films were etched off. It should be emphasized that the twin structures shown in Figs. 2(b) and 2(c) are the twin domains of LAO single crystals, not in YBCO films. It is known that PLD-processed YBCO films have small growth islands due to the screw dislocations, which results in microtwins usually crossed 90°. Our subsequent TEM examination of the YBCO-LAO interface confirmed that there was no correlation between the twinning in the YBCO film and that in the LAO substrate.

The dotted areas shown in Figs. 2(b) and 2(c) were free of processing defects, and hence used for direct transport measurements of J_c after MOI and AFM analysis. In the twin-free area, a 34 μ m wide bridge, shown at the bottom of Fig. 2(b), was patterned by focused laser beam. In the twin-rich area, two bridges, shown at the bottom of Fig. 2(c), were patterned with one (31 μ m wide, horizontal) parallel to the substrate twin domain boundaries, while the other (36 μ m wide, vertical) perpendicular to the twin domain boundaries.

Figures 2(d) and 2(e) are the AFM images of the film in the twin-free and twin-rich regions, respectively. In the twin-free region, the average size of the YBCO growth island is $\sim\!0.3~\mu\mathrm{m}$ with mean surface roughness $\sim\!5$ nm, while in the twin-rich region, it is $\sim\!0.7~\mu\mathrm{m}$ with mean surface roughness $\sim\!9$ nm. It is important to note that the excessive surface roughness on the films in the twin-rich region ($\sim\!4$ nm) is consistent with the expected relief depth of $\sim\!4.5$ nm due to the surface reconstruction there.

To determine the local J_c in the YBCO films at both the twin-free and the twin-rich regions, we performed a detailed analysis of the MOI images taken at various temperatures and fields. For simplicity, we employed the Bean critical state model with a field-independent J_c for a type II superconducting narrow strip of width w and thickness d under perpendicular B_a . J_c is determined by measuring the position of the flux front in a ZFC superconducting film, via the formula $2a/w=1/\cosh(B_a/B_d)$, where a is a distance between the flux front and the center line of the strip, and $B_d = \mu_0 J_c d/2$. A detailed description of this formula can be found in Refs. 7, 8, and 10. At 77 K, corresponding values of J_c at twin-free $(J_c^{f,M})$ and twin-rich $(J_c^{r,M})$ areas were 4.2 \times 106 and 6.2 \times 106 A/cm².

For unambiguous confirmation, we performed direct transport J_c measurements of each microbridge at liquid nitrogen temperature using 0.5 ms (settle time) pulse current to AIP license or convigant see http://apl.aip.org/apl/convigant isp

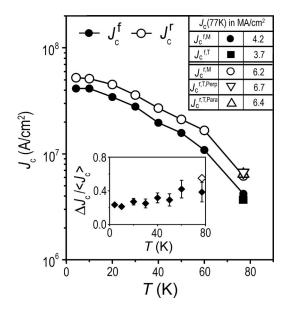


FIG. 3. Temperature dependence of MOI determined J_c in the twin-free (J_c^f , solid symbols) and the twin-rich (J_c^r , open symbols) regions. The inset figure shows the relative J_c enhancement at the twin-rich region, while the inset table lists all J_c values determined at 77 K using either MOI (M) or direct transport (T) method.

avoid sample heating. We obtained direct transport $J_c^{f,T} = 3.7 \times 10^6 \; \text{A/cm}^2$ at 77 K in the twin-free region, whereas in the twin-rich region, $J_c^{r,T,\text{Para}} = 6.4 \times 10^6 \; \text{A/cm}^2$ for the bridge parallel to the twin domain boundaries, and $J_c^{r,T,\text{Perp}} = 6.7 \times 10^6 \; \text{A/cm}^2$ for the bridge perpendicular to the twin domain boundaries. A table inset to Fig. 3 lists all J_c values determined at 77 K, clearly showing consistent J_c values determined by MOI and direct transport methods. It is quite remarkable that the corrugated substrate surface enhances flux pinning, and results in an increase of J_c in YBCO film of over 30% at 77 K. Furthermore, both MOI and transport measurements showed negligible J_c anisotropy in the twinrich region with respect to current flowing directions parallel or perpendicular to the LAO substrate domain boundaries.

Figure 3 shows the relative J_c enhancement, expressed as $\Delta J_c/\langle J_c\rangle \equiv 2(J_c^r - J_c^f)/(J_c^r + J_c^f)$, as a function of T. $\Delta J_c/\langle J_c\rangle$ is in general >25% and slowly increases as T increases. The detailed investigation of the origin of the pinning by the corrugated substrate surface is beyond the scope of the present work. Surface pinning due to the variation of vortex line energy is typically cited as a source of enhanced pinning related to the corrugated surface. However, the different surface morphologies observed from the AFM studies at the twin-free and twin-rich regions could suggest that this corrugation might have induced additional structural defects during the growth of YBCO films, and that contributed more pinning. In the epitaxial YBCO thin films grown on vicinal STO (001) surface, Jooss and co-workers reported enhanced vortex pinning due to strong quasiparticle scattering at an antiphase boundary.11

Finally, it should be emphasized that our observation of J_c enhancement in YBCO films by the nanoscaled substrate surface roughness is fundamentally different from the earlier MOI studies on the effect of twin boundaries *inside* the YBCO single crystals on flux motion. In the unidirectional twinned YBCO single crystals, several earlier studies reported a preferential flux penetration along the twin bound-

ary (or anisotropic flux pinning). 12 Unlike YBCO single crystals, our PLD-processed YBCO films have microtwins in each growth island, generally crossed 90° throughout the film, and hence are completely independent of the twin domain structures observed in the underlying LAO substrates. AFM images showed no observable difference in the film surface morphology parallel or perpendicular to the twin domains in the LAO substrate. Both direct transport measurements and MOI images, showing flux penetration length is the same along or across the twin domain boundaries in LAO, clearly indicate the feature of an isotropic pinning force. This observation is perhaps different from our perception that the corrugation might introduce directional structural defects in YBCO films, for example, antiphase boundaries, thus producing J_c anisotropy. Nonetheless, our observation is consistent with numerous reports on PLDgrown YBCO films on a twinned LAO substrate, where J_c anisotropy has never been found.

In summary, a coordinated analysis of MOI, direct transport, optical microscopy, AFM, and TEM in YBCO film grown by PLD on LAO substrate revealed a remarkable 30% enhancement of J_c due to nanoscaled substrate surface roughness. This unambiguous finding in the case of PLD-processed films suggests that some level of nanoscaled surface roughness on the buffered metal substrate might in fact help to improve the flux pinning capability in coated conductors, provided that the overlaying YBCO films can be grown satisfactorily.

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¹For a comprehensive review, see the book *Next Generation High Temperature Superconducting Wires*, edited by A. Goyal (Plenum, New York, 2003).

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